TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHC153F, TC74VHC153FN, TC74VHC153FS, TC74VHC153FT

DUAL 4 - CHANNEL MULTIPLEXER

The TC74VHC153 is an advanced high speed CMOS DUAL 4-CHANNEL MULTIPLEXERs fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Each of these data (1C0 - 1C3, 2C0 - 2C3) is selected by the two address inputs A and B.

Separate strobe inputs $(\overline{1G}, 2\overline{G})$ are provided for each of the two four-line sections.

The strobe input (\overline{G}) can be used to inhibit the data output; the output is fixed in low level while the strobe input is held high.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES:

- High Speed------ $t_{pd} = 5.0ns(typ.)$ at $V_{CC} = 5V$
- Low Power Dissipation $I_{CC} = 4\mu A(Max.)$ at Ta = 25°C
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range V_{CC} (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74ALS153

TRUTH TABLE

| SELECT INPUTS | | | DATA | INPUTS | STROBE | OUTPUTS | | | | |
|------------------|----------------|-----|---------|--------|--------|---------|---|--|--|--|
| В | A | C 0 | C1 C2 C | | C 3 | G | Y | | | |
| Х | X | Х | X | X | X | Н | L | | | |
| L | L | L | X | X | Х | L | L | | | |
| L | L | н | X | X | X | L | Н | | | |
| L | Н | Х | L | X | X | L | L | | | |
| L | н | Х | н | X | X | L | Н | | | |
| н | L | Х | X | L | X | L | L | | | |
| Н | L | Х | X | н | X | L | Н | | | |
| Н | Н | Х | X | X | L | L | L | | | |
| Н | Н | Х | Х | Х | Н | L | Н | | | |
| X : C | X : Don't Care | | | | | | | | | |



IEC LOGIC SYMBOL

7

8

1C2 4

1C1 5

1C0 6

1Y

GND



(TOP VIEW)

961001EBA2

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

13 2C3

11

10

9 2Y

12 2C2

2C1

2C0

SYSTEM DIAGRAM



961001EBA2'

The products described in this document are subject to foreign exchange and foreign trade control laws.
The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
The information contained herein is subject to change without notice.

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | VALUE | UNIT |
|------------------------------------|------------------|---------------------------|------|
| Supply Voltage Range | V _{cc} | -0.5~7.0 | V |
| DC Input Voltage | VIN | -0.5~7.0 | V |
| DC Output Voltage | V _{OUT} | -0.5~V _{CC} +0.5 | V |
| Input Diode Current | Ι _{ικ} | - 20 | mA |
| Output Diode Current | Ι _{οκ} | ± 20 | mA |
| DC Output Current | I _{OUT} | ±25 | mA |
| DC V _{CC} /Ground Current | I _{cc} | ± 50 | mA |
| Power Dissipation | P _D | 180 | mW |
| Storage Temperature | T _{stg} | -65~150 | °C |

RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | VALUE | UNIT |
|--------------------------|------------------|---|--------|
| Supply Voltage | V _{cc} | 2.0~5.5 | V |
| Input Voltage | VIN | 0~5.5 | V |
| Output Voltage | V _{OUT} | 0~V _{cc} | V |
| Operating Temperature | T _{opr} | - 40~85 | °C |
| Input Rise and Fall Time | dt/dv | 0~ 100 (Vcc = 3.3 ± 0.3V) 0~ 20 (Vcc = 5 ± 0.5V) | ns / V |

DC ELECTRICAL CHARACTERISTICS

| PARAMETER | SYMBOL | TEST CONDITION | | V _{cc} | Ta = 25°C | | Ta = - 40~85°C | | UNIT | |
|--------------------------------|-----------------|------------------------------------|------------------------------------|-----------------------|--------------|---------------------|-----------------------|---------------------|--------------|----|
| FARAIMETER | STIVIBUL | | | (V) | MIN. | TYP. | MAX. | MIN. | MAX. | |
| High - Level | | | | 2.0 | 1.50 | — | — | 1.50 | — | |
| Input Voltage | VIH | | 3.0~ 5.5 | V _{cc} × 0.7 | _ | _ | V _{cc} × 0.7 | _ | V | |
| Low - Level | | | 2.0 | | - | 0.50 | — | 0.50 | v | |
| Input Voltage | V _{IL} | | 3.0~ 5.5 | — | - | $V_{cc} \times 0.3$ | — | $V_{cc} \times 0.3$ | | |
| | | V _{1 N} = | $I_{OH} = -50 \mu A$ | 2.0 | 1.9 | 2.0 | — | 1.9 | — | v |
| High - Level Output Voltage | V _{он} | | | 3.0 4.5 | 2.9 4.4 | 3.0 4.5 | | 2.9 4.4 | _ | |
| | | V _{IH} or V _{IL} | $I_{OH} = -4mA$ $I_{OH} = -8mA$ | 3.0 4.5 | 2.58 3.94 | _ | _ | 2.48 3.80 | _ | |
| | V _{OL} | V _{1N} = | I _{OL} = 50μA | 2.0 3.0 | _ | 0.0 0.0 | 0.1 | _ | 0.1 0.1 | |
| Low - Level Output Voltage | | | | 4.5 | — | 0.0 | 0.1 | — | 0.1 | V |
| | | V _{IH} or V _{IL} | $I_{OL} = 4mA$ $I_{OL} = 8mA$ | 3.0 4.5 | - | | 0.36 0.36 | _ | 0.44 0.44 | |
| Input Leakage Current | I _{IN} | $V_{1N} = 5.5V \text{ or } G$ | 0~5.5 | - | — | ±0.1 | - | ± 1.0 | | |
| Quiescent Supply Current | I _{cc} | $V_{1N} = V_{CC}$ or GND | | 5.5 | - | _ | 4.0 | _ | 40.0 | μΑ |

| PARAMETER | SYMBOL | TES | TEST CONDITION | | Ta = 25°C | | | Ta = - 40~85°C | | UNIT |
|-------------------------------|--------------------------------------|----------|---------------------|---------|-----------|------|------|----------------|------|------|
| FARAIVIETER | STIVIBOL | | V _{cc} (V) | CL (pF) | MIN. | TYP. | MAX. | MIN. | MAX. | |
| | | | 3.3 ± 0.3 | 15 | — | 7.7 | 11.9 | 1.0 | 14.0 | ns |
| Propagation Delay Time | t _{pLH} | | | 50 | — | 10.2 | 15.4 | 1.0 | 17.5 | |
| (Cn-Y) | t _{pHL} | | 5.0 ± 0.5 | 15 | — | 5.0 | 7.7 | 1.0 | 9.0 | |
| (, | | | | 50 | — | 6.5 | 9.7 | 1.0 | 11.0 | |
| | t _{pLH} | | 3.3±0.3 | 15 | — | 10.8 | 16.7 | 1.0 | 19.5 | |
| Propagation Delay Time | | | | 50 | — | 13.3 | 20.2 | 1.0 | 23.0 | |
| (A,B-Y) | t _{pLH} t _{pHL} | | 5.0±0.5 | 15 | — | 6.8 | 9.9 | 1.0 | 11.5 | |
| (,,_ ,, | | | 5.0 ± 0.5 | 50 | — | 8.3 | 11.9 | 1.0 | 13.5 | |
| | t _{pLH} t _{pHL} | | 3.3±0.3 | 15 | — | 6.3 | 10.1 | 1.0 | 12.0 | |
| Propagation Delay Time | | | | 50 | — | 8.8 | 13.6 | 1.0 | 15.5 | |
| $(\overline{G}-Y)$ | | | 5.0 ± 0.5 | 15 | — | 4.4 | 6.4 | 1.0 | 7.5 | |
| | | | | 50 | — | 5.9 | 8.4 | 1.0 | 9.5 | |
| Input Capacitance | C _{IN} | | | | — | 4 | 10 | _ | 10 | E |
| Power Dissipation Capacitance | C _{PD} | (Note 1) | | | _ | 20 | _ | _ | _ | pF |

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

 $I_{CC \text{(opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

INPUT EQUIVALENT CIRCUIT







Unit in mm



SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150-1.27)



SSOP 16PIN OUTLINE DRAWING (SSOP16-P-225-0.65B)





TSSOP 16PIN OUTLINE DRAWING (TSSOP16-P-0044-0.65)



Unit in mm